





FORM PTO-1449 INFORMATION DISCLOSURE STATEMENT 	MMB DOCKET NO. 1890-0079	APPLICATION NO.: 10/826,921
	APPLICANT(S): Taddiken	
	FILING DATE: April 16, 2004	GROUP ART UNIT: 2811

U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						


  

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	AL						Yes No
	AM						Yes No
	AN						Yes No
	AO						Yes No
	AP						Yes No

OTHER (Including Author, Title, Date, Pertinent Pages, etc.)			
	AQ	1	Gebara, Edward, Niklas Rorsman, Jörgen Olsson, Herbert Zirath, Klas Håkan Eklund, "Output Power Characteristics of High Voltage LDMOS Transistors," Proceedings of the 5 <sup>th</sup> Symposium on Gigahertz Electronics, Goeteborg, Sweden, March 2000, pages 75-78, (4 pages).
	AR	1	Disney, D. R., A. K. Paul, M. Darwish, R. Basecki, V. Rumennik, "A New 800V Lateral MOSFET With Dual Conduction Paths," Proceedings of the 13 <sup>th</sup> International Symposium on Power Semiconductor Devices & ICs, Osaka, Japan, June 2001, pages 399-402, (4 pages).
	AS	1	Cai, Jun, Changhong Ren, N. Balasubramanian, Johnny K. O. Sin, "A Novel High Performance Stacked LDD RF LDMOSFET," IEEE Electron Device Letters, Vol. 22, No. 5, May 2001, (3 pages).

EXAMINER 	DATE CONSIDERED 2/6/06
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicants.


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	FILING DATE: April 16, 2004	GROUP ART UNIT: 2811 <i>2815</i>

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
	BA						
	BB						
	BC						
	BD						
	BE						
	BF						
	BG						
	BH						
	BI						
	BJ						
	BK						

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	BL						Yes No
	BM						Yes No
	BN						Yes No
	BO						Yes No
	BP						Yes No

## OTHER (Including Author, Title, Date, Pertinent Pages, etc.)

	BQ	2	Söderbärg, A., B. Edholm, J. Olsson, F. Masszi and K. H. Eklund, "Integration of a Novel High-Voltage Giga-Hertz DMOS Transistor into a Standard CMOS Process," IEEE, 1995, pages 38.5.1-38.5.4, (4 pages).
	BR	2	
	BS	2	

EXAMINER

DATE CONSIDERED

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